

1 Product profile

1.1 General description

Two planar PIN diodes in series configuration in a SOT23 small plastic SMD package.

1.2 Features and benefits

- · High voltage, current controlled
- RF resistor for RF attenuators and switches
- · Low diode capacitance
- · Low diode forward resistance
- · Low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

1.3 Applications

· RF attenuators and switches

2 Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	anode		_
2	cathode	3	3
3	common connection	top view	1 2 sym135

3 Ordering information

Table 2. Ordering information

Type number	Package					
	Name	Description	Version			
BAP64-04	-	plastic surface-mounted package; 3 leads	SOT23			



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4 Marking

Table 3. Marking

Tubio o. marking					
Type number Marking Description		Description			
BAP64-04 4K*		* = t : made in Malaysia			
		* = W : made in China			

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Values are specified per diode.

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	175	V
I _F	forward current		-	100	mA
P _{tot}	total power dissipation	T _{sp} = 90 °C	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6 Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		220	K/W

7 Characteristics

Table 6. Characteristics

Values are specified per diode; T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _F	forward voltage	I _F = 50 mA		-	0.95	1.1	V
I_R	reverse current	V _R = 60 V		-	-	10	μΑ
		V _R = 20 V		-	-	1	μΑ
C_d	diode capacitance	see Figure 1; f = 1 MHz;					
		V _R = 0 V		-	0.52	-	pF
		V _R = 1 V		-	0.37	-	pF
		V _R = 20 V		-	0.23	0.35	pF
r_D	diode forward resistance	see Figure 2; f = 100 MHz;	[1]				
		I _F = 0.5 mA		-	20	40	Ω
		I _F = 1 mA		-	10	20	Ω
		I _F = 10 mA		-	2.0	3.8	Ω

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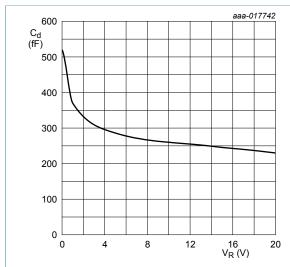
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		I _F = 100 mA	-	0.7	1.35	Ω
Τ _L	charge carrier life time	when switched from I _F = 10 mA to I _R = 6 mA; R _L = 100 Ω ; measured at I _R = 3 mA	-	1.55	-	μs
L _S	series inductance		-	1.4	-	nH

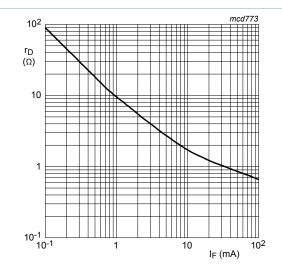
[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.

7.1 Graphical data



 $f = 1 MHz; T_i = 25 °C.$

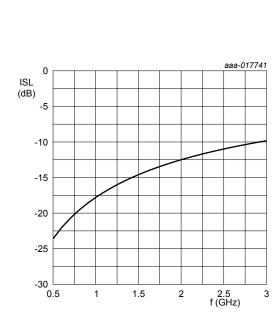
Figure 1. Diode capacitance as a function of reverse voltage; typical values



 $f = 100 \text{ MHz}; T_i = 25 ^{\circ}\text{C}.$

Figure 2. Forward resistance as a function of forward current; typical values

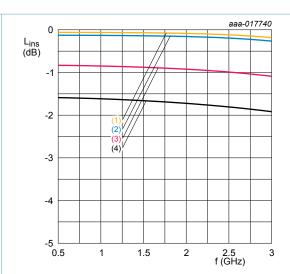
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 T_{amb} = 25 °C

Diode zero biased and inserted in series with a 50 Ω stripline circuit

Figure 3. Isolation of the diode as a function of frequency; typical values



T_{amb} = 25 °C

1. I_F = 100 mA

2. $I_F = 10 \text{ mA}$

3. $I_F = 1 \text{ mA}$

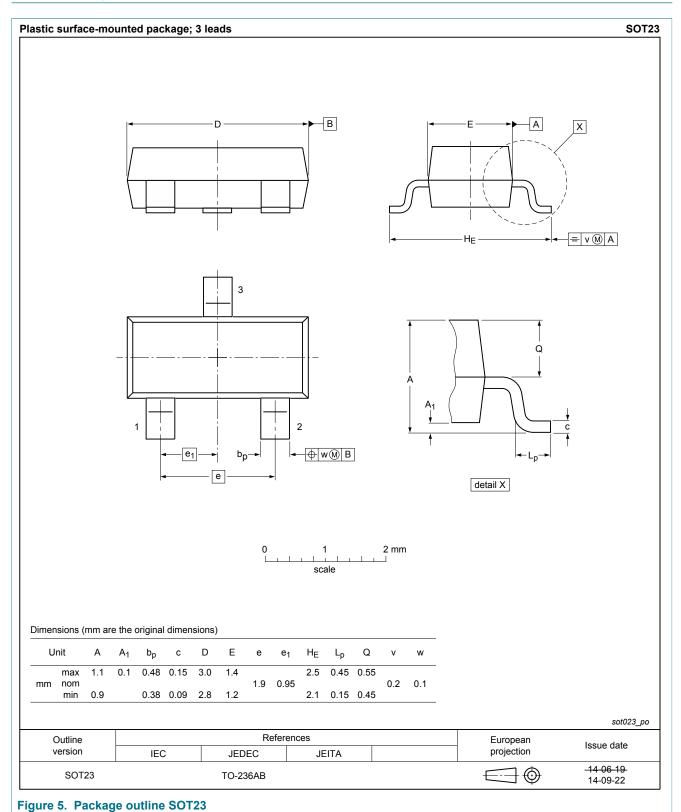
4. $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

Figure 4. Insertion loss of the diode as a function of frequency; typical values

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8 Package outline



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9 Abbreviations

Table 7. Abbreviations

Acronym	Description
AQL	acceptable quality level
PIN	P-type, intrinsic, N-type
SMD	surface mounted device
S4	special inspection level 4

10 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP64-04 v.6	20190311	Product data sheet	-	BAP64-04 v.5
Modifications:	• changed V _R cond	dition of I _R from 175 V to 60 V		
BAP64-04 v.5	20150428	Product data sheet	-	BAP64-04 v.4
Modifications:	of NXP Semicon	been adapted to the new comp	. ,	, ,
BAP64-04 v.4 (9397 750 06424)	19990921	Product specification	-	BAP64-04 v.3
BAP64-04 v.3 (9397 750 06282)	19990827	Product specification	-	BAP64-04_N v.2
BAP64-04_N v.2 (9397 750 06088)	19990616	Preliminary specification	-	BAP64-04 v.1
BAP64-04 v.1 (9397 750 05559)	19990510	Objective specification	-	-

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11 Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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